

N-Channel Silicon MOSFET

MCH6402



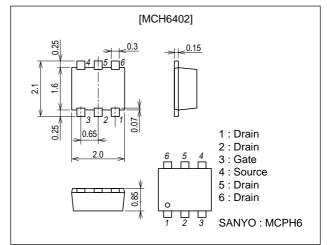
# **Ultrahigh-Speed Switching Applications**

### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

## **Package Dimensions**

unit : mm 2193A



# **Specifications**

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	16	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0		2.4	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =2A	2.4	3.5		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =2A, V <sub>G</sub> S=10V		50	65	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =1A, V <sub>G</sub> S=4V		100	140	mΩ

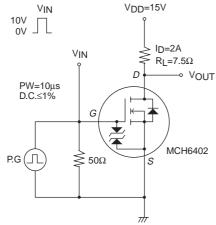
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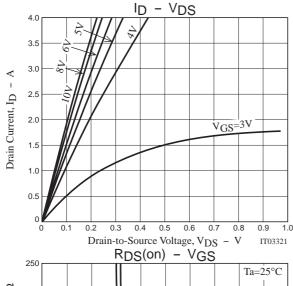
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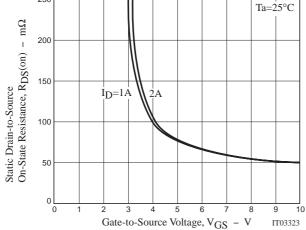
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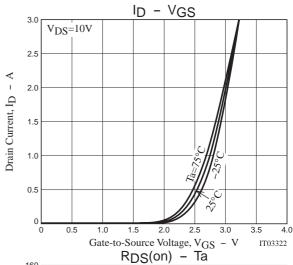
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		270		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		90		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		55		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit		9		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit		28		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit		24		ns
Fall Time	tf	See specified Test Circuit		16		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A		7		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A		1.3		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A		1.5		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =4A, V <sub>GS</sub> =0		0.84	1.2	V

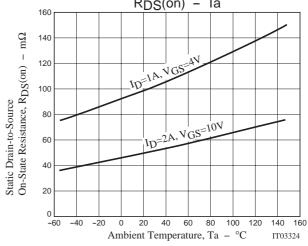
# **Switching Time Test Circuit**

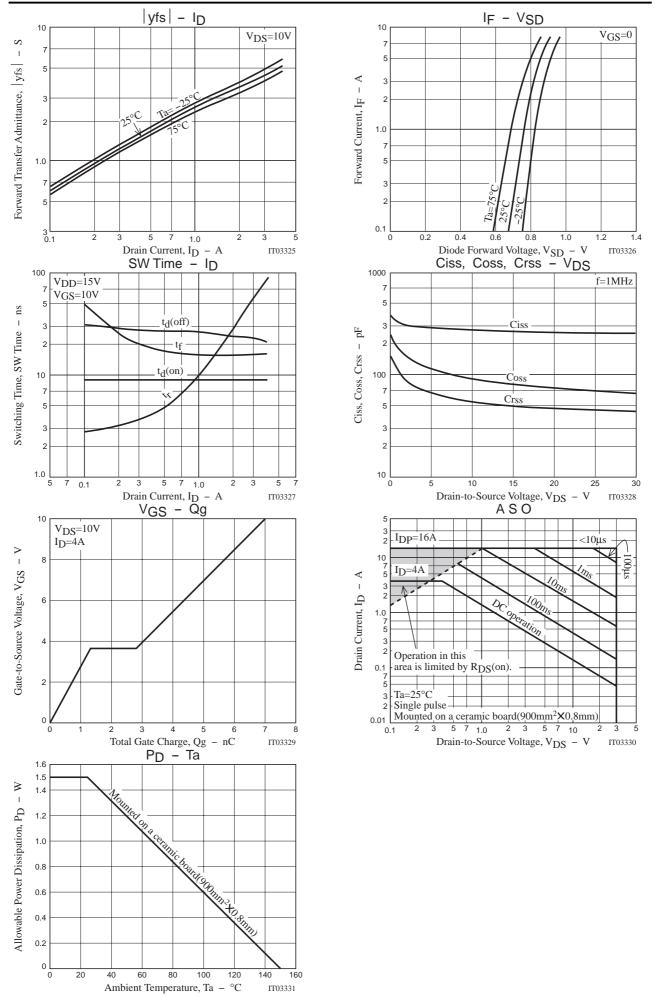












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